

10Amp. Trench Schottky Ultra Low RECTIFIER

SKT10100E3

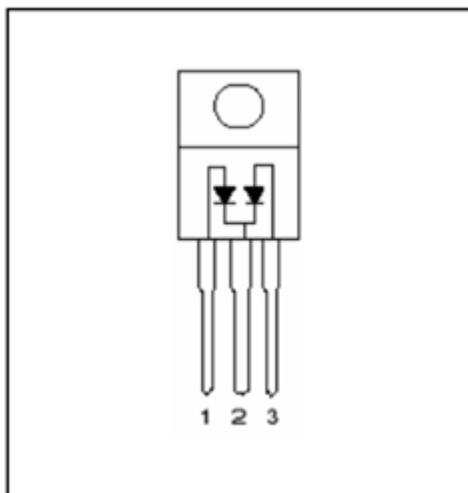
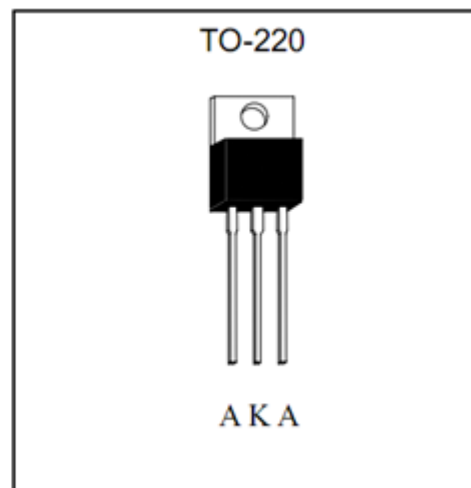
| | |
|----------------|--------|
| $I_{F(AV)}$ | 2 x 5A |
| V_{RRM} | 100V |
| V_F at 125°C | 0.58V |
| T_j | 150°C |

Features

- 150°C operating junction temperature
- Softest, fast switching capability
- High reverse surge capability
- Reduced ultra-low forward voltage drop (VF) ; better efficiency and cooler operation.
- Lead-Free Finish; RoHS Compliant
- Trench technology provides a superior avalanche capability

Mechanical Data

- Case: JEDEC TO-220 molded plastic
- Weight: 2.24 grams approximately
- Terminals: Pure tin plated, lead-free, solderable per MIL-STD-750 method 2026
- Epoxy: UL 94V-0 rate flame retardant
- Polarity: As marked.
- Mounting Torque: 5 in-lbs max

Equivalent Circuit

Outline




Maximum Ratings and Electrical Characteristics

(Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.)

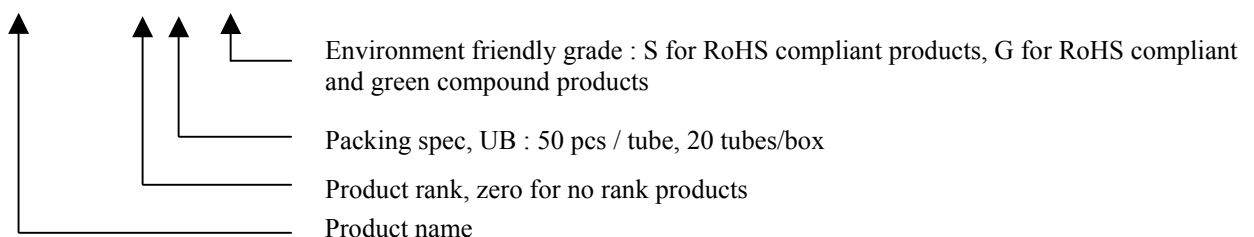
| Parameter | Symbol | Min. | Typ. | Max. | Units |
|---|---------------------|--|------|------|-------|
| Maximum DC blocking voltage | V _{DC} | | | 100 | V |
| Maximum Recurrent peak reverse voltage | V _R RM | | | 100 | V |
| Maximum RMS voltage | V _R MS | | | 70 | V |
| instantaneous forward voltage at I _F =2A per diode | V _F | T _C =25°C | 0.39 | - | V |
| | | T _C =125°C | 0.35 | - | |
| instantaneous forward voltage at I _F =5A per diode | V _F | T _C =25°C | 0.65 | 0.72 | V |
| | | T _C =125°C | 0.58 | 0.66 | |
| Reverse current per diode | I _R | V _R =100 V, T _C =25°C | 25 | 80 | μA |
| | | V _R =100 V, T _C =125°C | 2 | 12 | mA |
| Maximum Average forward rectified current per device | I _F (AV) | | | 10 | A |
| Maximum Average forward rectified current per diode | I _F (AV) | | | 5 | A |
| Non-repetitive peak forward surge current @ 8.3ms single half sine wave superimposed on rated load (JEDEC method) per diode | I _F SM | 80 | | | A |
| Peak Repetitive Reverse Surge Current (2uS-1Khz) | I _{RRM} | | | 2 | A |
| Storage temperature range | T _{stg} | -55 | | 150 | °C |
| Operating junction temperature range | T _J | -55 | | 150 | °C |

Thermal Data

| Parameter | Symbol | Value | Unit |
|---|---------------------|-------|------|
| Typical Thermal Resistance, Junction-to-case | R _{th,j-c} | 2 | °C/W |
| Typical Thermal Resistance, Junction-to-ambient | R _{th,j-a} | 60 | °C/W |

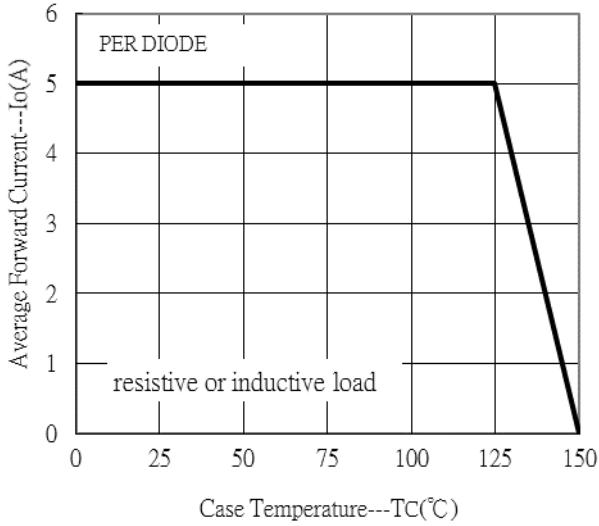
Ordering Information

| Device | Package | Shipping |
|-------------------|-----------------------------------|---|
| SKT10100E3-0-UB-S | TO-220 (Pb-free lead plating) | 50 pcs/tube, 20tubes/box, 4boxes/carton |

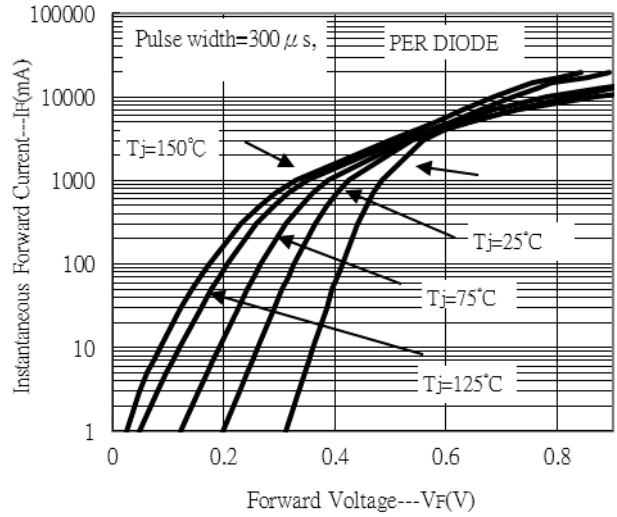


Typical Characteristics

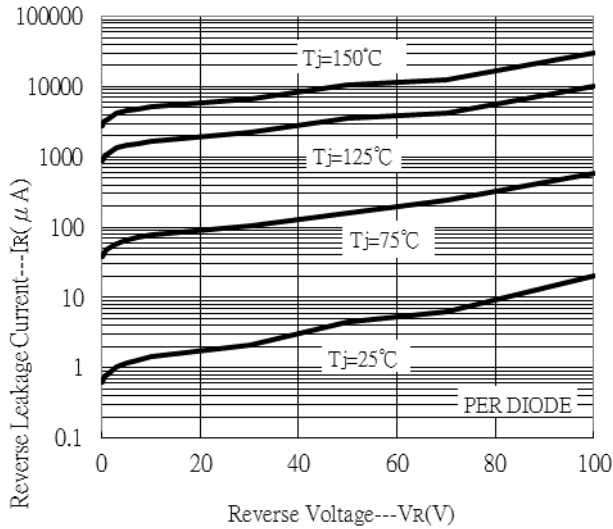
Forward Current Derating Curve



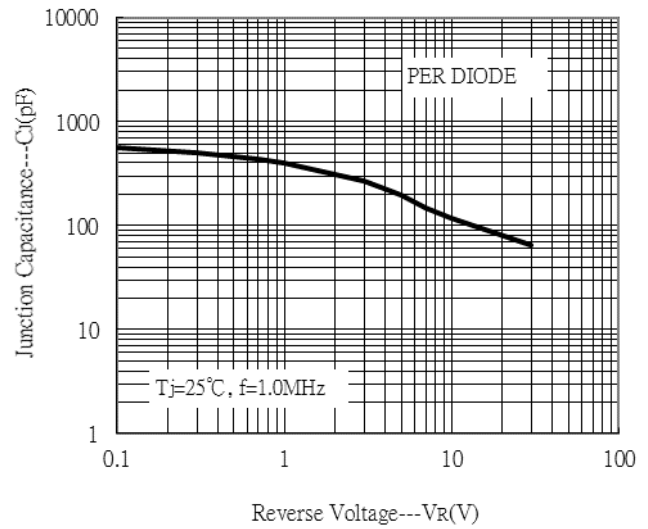
Forward Current vs Forward Voltage



Reverse Leakage Current vs Reverse Voltage

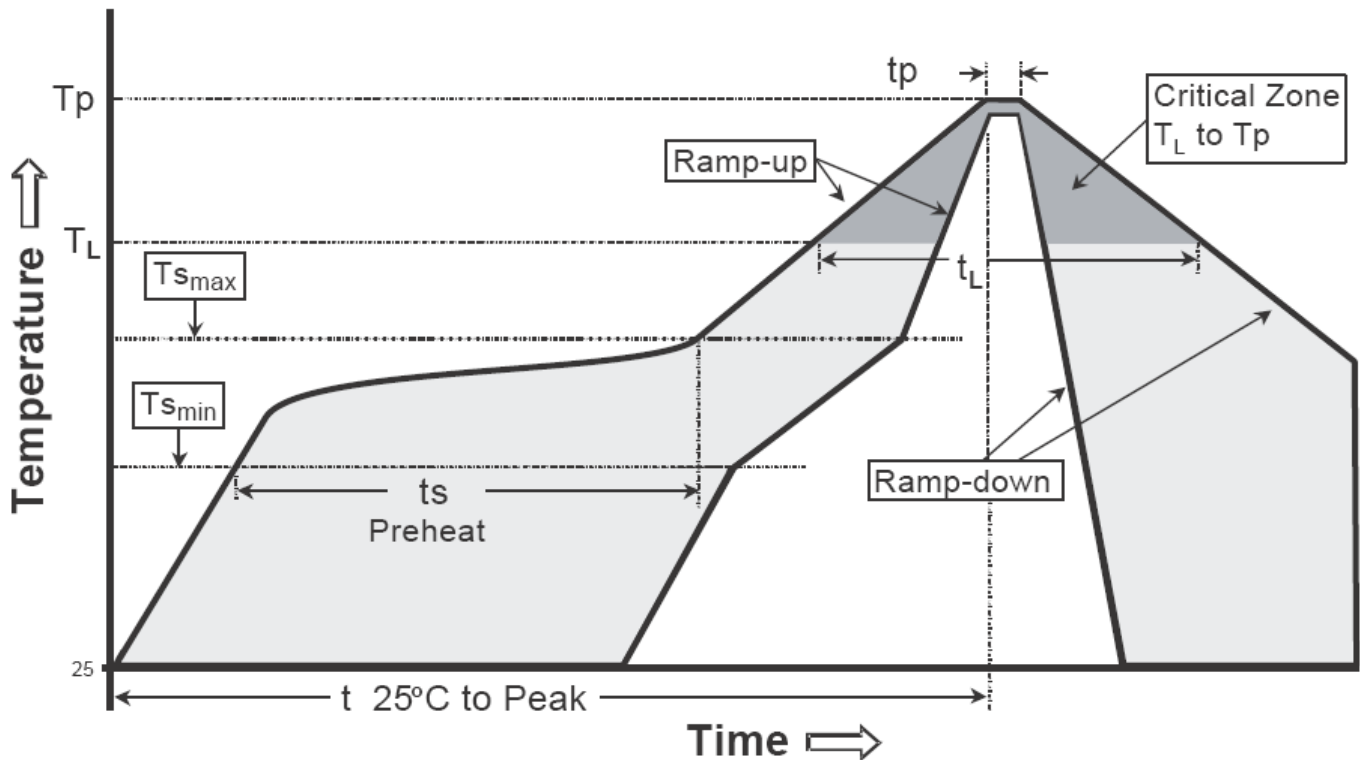


Junction Capacitance vs Reverse Voltage



Recommended wave soldering condition

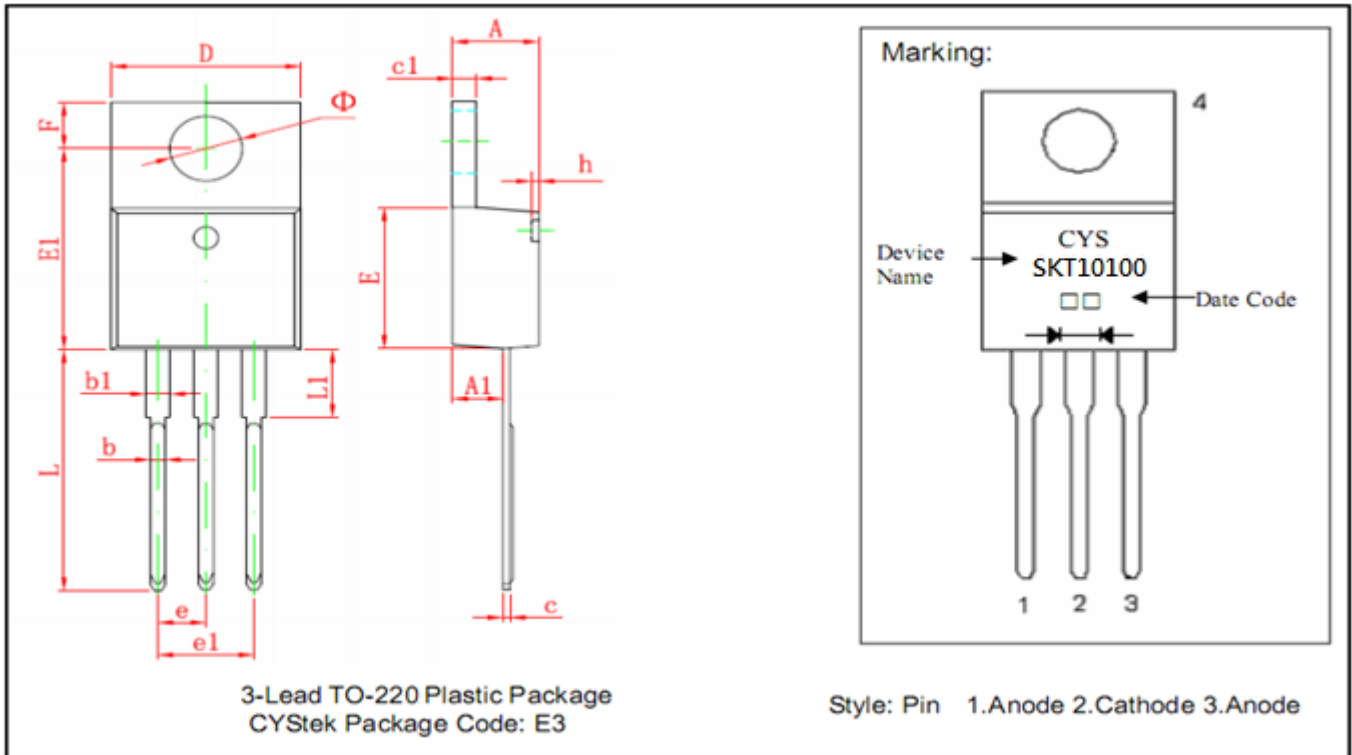
| | | |
|-----------------|------------------|-----------------|
| Product | Peak Temperature | Soldering Time |
| Pb-free devices | 260 +0/-5 °C | 5 +1/-1 seconds |

Recommended temperature profile for IR reflow


| Profile feature | Sn-Pb eutectic Assembly | Pb-free Assembly |
|---|-------------------------|------------------|
| Average ramp-up rate (T _{smax} to T _p) | 3°C/second max. | 3°C/second max. |
| Preheat | | |
| -Temperature Min(T _{s min}) | 100°C | 150°C |
| -Temperature Max(T _{s max}) | 150°C | 200°C |
| -Time(t _{s min} to t _{s max}) | 60-120 seconds | 60-180 seconds |
| Time maintained above: | | |
| -Temperature (T _L) | 183°C | 217°C |
| - Time (t _L) | 60-150 seconds | 60-150 seconds |
| Peak Temperature(T _P) | 240 +0/-5 °C | 260 +0/-5 °C |
| Time within 5°C of actual peak temperature(t _p) | 10-30 seconds | 20-40 seconds |
| Ramp down rate | 6°C/second max. | 6°C/second max. |
| Time 25 °C to peak temperature | 6 minutes max. | 8 minutes max. |

Note : All temperatures refer to topside of the package, measured on the package body surface.

TO-220 Dimension



*: Typical

| DIM | Millimeters | | Inches | | DIM | Millimeters | | Inches | |
|-----|-------------|--------|--------|-------|--------|-------------|--------|--------|-------|
| | Min. | Max. | Min. | Max. | | Min. | Max. | Min. | Max. |
| A | 4.470 | 4.670 | 0.176 | 0.184 | E1 | 12.060 | 12.460 | 0.475 | 0.491 |
| A1 | 2.520 | 2.820 | 0.099 | 0.111 | e | 2.540* | | 0.100* | |
| b | 0.710 | 0.910 | 0.028 | 0.036 | e1 | 4.980 | 5.180 | 0.196 | 0.204 |
| b1 | 1.170 | 1.370 | 0.046 | 0.054 | F | 2.590 | 2.890 | 0.102 | 0.114 |
| c | 0.310 | 0.530 | 0.012 | 0.021 | h | 0.000 | 0.300 | 0.000 | 0.012 |
| c1 | 1.170 | 1.370 | 0.046 | 0.054 | L | 13.400 | 13.800 | 0.528 | 0.543 |
| D | 10.010 | 10.310 | 0.394 | 0.406 | L1 | 3.560 | 3.960 | 0.140 | 0.156 |
| E | 8.500 | 8.900 | 0.335 | 0.350 | Φ | 3.735 | 3.935 | 0.147 | 0.155 |

Notes: 1.Controlling dimension: millimeters.
 2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.
 3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead: Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.

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